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# AZABODIPY aggregates as a promising electroluminescent material for sustainable NIR OLED applications†

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Organic materials capable of emission in the near infrared (NIR) spectral range are of great interest for many branches of science and technology. In this work we investigate a NIR emitting molecule (DTDPAB) based on 4,4-difluoro-4-bora-3a,4a-diaza-s-indacene (BODIPY) modified with nitrogen substitution at the carbon *meso* position (AZABODIPY) and thiophens and phenyls substituents. The thienyl substituents decrease the energy band gap of the molecule with respect to standard AZABODIPY and the emission spectrum results strongly shifted to the lower energies. The molecule is employed as a dopant in commercial and suitably synthesized polymers used as hosts in solution-processable emitting layers of organic light-emitting diodes (OLEDs). After device architecture optimization the electroluminescence in pure NIR (>700 nm) with the maximum at 910 nm is achieved. To our knowledge, this is the first example of electroluminescence from a single AZABODIPY emitter in real NIR, which adds another type of electrically excitable organic luminophore to the family of NIR emitting materials.

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## Introduction

The demand for materials capable of emitting in the near-infrared (NIR), the electromagnetic radiation in the wavelength range between 700 and 2500 nm, is constantly growing. This spectral range is useful for many applications such as sensors, optical communication, night vision, biometric identification, etc.<sup>1–4</sup>

NIR organic emitters are particularly interesting because they can combine the characteristics of lightness, transparency, and flexibility with the demands of low toxicity and abundance of raw materials, or even better, raw materials that are renewable or derived from waste. This request is representative of the circular economy scheme, one of the pillars of current sustainable development.

The field of organic emitting materials ranges from small molecules to polymers and involves different photophysical

mechanisms such as fluorescence, phosphorescence, energy transfer, TADF (thermally activated delayed fluorescence) and AIE (aggregation-induced emission).<sup>5–9</sup>

The results obtained by applying these materials for example in OLED devices are manifold. In fact, since the pioneering work of Tang and VanSlyke in 1987, OLEDs are now one of the best display technologies in the industry with many electronic appliances, such as TV screens, or smartwatches or mobile phones or cameras. This is due to noteworthy advantages, such as low cost, low-driving voltage, light weightiness, and fast response.<sup>10</sup> Furthermore, this technology was regarded as the future major display and lighting technology with application in sensing, biomedicine or automotive.<sup>11</sup>

Satisfactory results have been obtained in OLEDs with emitting materials from blue to red and with white emission, while the demand for good emitters in NIR is still open.<sup>12–16</sup> In fact, currently the main NIR emitters are based on rare earths which have a limited availability and are unevenly distributed in different countries. Therefore, organic materials have been extensively studied for their emissive properties, especially for biolabeling in solution. Recently OLED devices with emission in the NIR zone have been developed thanks to a proper choice of the number, type and position of substituents.<sup>2,17–21</sup>

Among the organic materials, BODIPY (4,4-difluoro-4-bora-3a,4a-diaza-s-indacene) derivatives are proving to be particularly promising for their chemical stability and excellent absorption and emission properties. Moreover, thanks to nine

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reactive positions, in BODIPY derivatives a fine modulation of the absorption and emission zone is allowed.<sup>22–26</sup>

To shift the emission towards the NIR region in 2002 Killoran *et al.* proposed the replacement of carbon in the meso position with a nitrogen leading to a new family of BODIPY derivatives, known as AZABODIPY, with a marked red shift of the absorption and emission window.<sup>27</sup> The formation of a C=N linkage isoelectronic with C=C bond but with different electronegativity favours the stabilization of the LUMO state reducing the energy gap. The AZABODIPY derivatives have already found application in solutions for sensing, biological detection and medical imaging<sup>28,29</sup> while examples of their use in OLEDs is not reported. The closest analogue employed as an emitter in electroluminescent diode is a dimeric aza-BODIPY called “pyrrolopyrrole” aza-BODIPY.<sup>30</sup> On the other hand, devices with reasonable efficiencies based on deep-red and NIR electroluminescence (EL) from BODIPY derivatives can be found in the literature.<sup>31–35</sup>

In the present work we propose the use in OLED of the asymmetric AZABODIPY which is substituted in 1 and 7 positions with phenyl rings and in 3 and 5 positions with thiophenic fragments (**DTDPAB**, see Scheme 1). The electron-rich thienyl moiety increases the delocalization (conjugation) with a consequent further shift of the absorption and emission towards low energies in the NIR zone.<sup>36,37</sup>

In rigid planar systems such as BODIPY derivatives, the formation of aggregates is one of the main causes of quenching combined with high nonradiative transition rate due to the energy gap law. In general these materials are dispersed in a host which decreases the aggregation quenching but causes an undesired blue shift of the emission.<sup>38,39</sup>

In this work we were able to exploit the emission of the aggregate in the real NIR at 910 nm in an OLED. We use the

standard approach of dispersing the dye in a host based on the commercial conjugated polymer **F8BT** and its derivative random copolymer synthesized in our laboratory **F8BT-TTBT** (see Scheme 1).<sup>40</sup> We were able to obtain a delicate balance between the quenching effect of the emission caused by the aggregation and the blue shift of the emission due to the dispersion of the organic molecule. In order to improve the effectiveness of our approach we modified the architecture of the devices, direct and inverted, the charge regulating layers, and the polymeric host. In fact, we have synthesized a new polymer *via* Suzuki random copolymerization of benzothiadiazole, 9,9-di-octylfluorene and 2,2'-bithiophene derivatives which shifted emission towards red spectral region with respect to standard **F8BT** in order to modulate energy transfer between the polymeric matrix and the dye. Through this approach we demonstrate that OLEDs spectrum can be adjusted depending on the applicative requirements of the device. By controlling the various parameters, we were able to modulate the emission of the device and finally the electroluminescence of the aggregates at 910 nm was obtained.

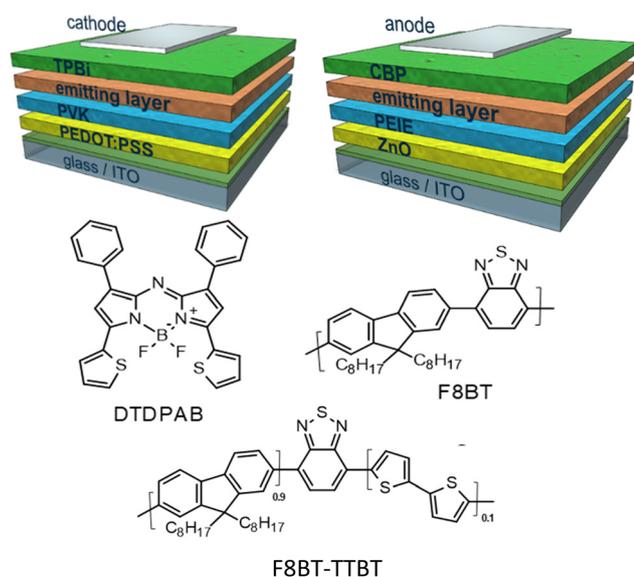
## Experimental

### Synthetic methods

**General information for synthesis.** All reagents were purchased from a commercial source and used without further purification. All solvents have been degassed bubbling nitrogen prior to use. All reactions are presented in Scheme 2 and in Scheme S1 in ESI† and were carried out in inert atmosphere. Scheme 1 shows the structures of employed polymers.

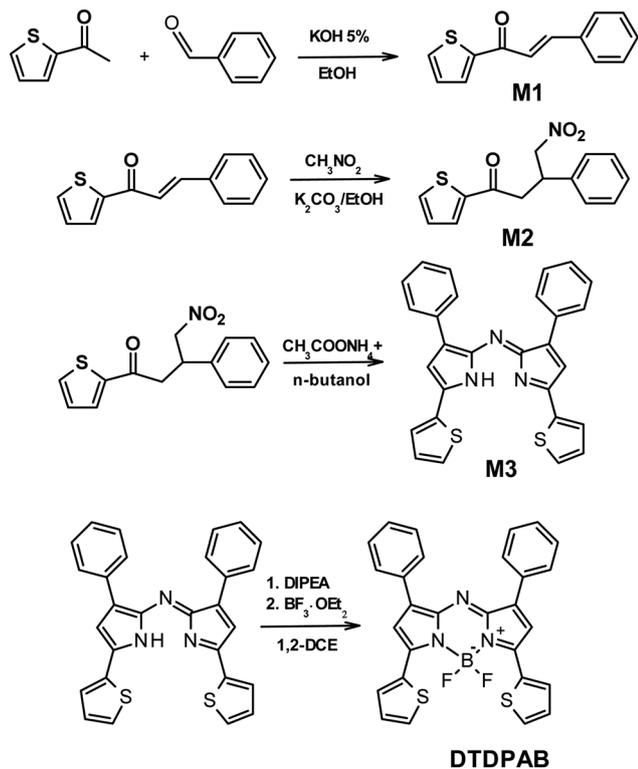
**Synthesis of monomer M1.** (See Scheme 2) A mixture of 2-acetylthiophene (5 g, 39.6 mmol, 1 eq.) and benzaldehyde (4.2 g, 39.6 mmol, 1 eq.) was added in a predegassed round bottom flask, followed by three vacuum/nitrogen cycles. Then degassed ethanol (200 ml) and potassium hydroxide (KOH) 5% solution (100 ml) in water were added. The mixture was left under stirring at room temperature. After 24 h a white precipitated is formed. The precipitated was filtered, washed with water and recrystallized from ethanol (8 g, 94% yield). <sup>1</sup>H NMR (600 MHz, DMSO) δ 8.35(d, 1H), 8.06 (d, 1H), 7.89 (m, 3H), 7.73 (d, 1H), 7.47 (m, 3H), 7.32 (m, 1H).

**Synthesis of monomer M2.** (See Scheme 2) A mixture of chalcone **M1** (3 g, 14 mmol, 1 eq.), nitro methane (4.27 g, 70 mmol, 5 eq.) and potassium carbonate (K<sub>2</sub>CO<sub>3</sub>, 39 mg, 2% mol) was added in a predegassed round bottom flask, followed by three vacuum/nitrogen cycles. Then degassed ethanol (14 ml) was added and the mixture was heated under stirring to reflux for 12 h. After cooling the mixture to room temperature, the solvent was removed under reduced pressure, the crude was then redissolved in ethyl acetate and washed three times with brine. The organic phase was then dried over sodium sulfate and the solvent removed to give a yellowish oil in quantitative yield. The compound was used in the next step without further purification.



**Scheme 1** General architectures of direct (left) and inverted (right) diodes used in this work together with structures of the materials applied in the emitting layers.





Scheme 2 Synthetic route for DTDPAB molecule.

**Synthesis of monomer M3.** (See Scheme 2) A mixture of 4-nitro-3-phenyl-1-(2-thienyl)butan-1-one (**M2**, 3.95 g, 14 mmol, 1 eq.) and ammonium acetate (37.7 mg, 490 mmol, 35 eq.) was dissolved in degassed butanol (185 ml) and left under stirring at reflux for 24 h. After cooling the crude to room temperature, the reaction mixture was diluted with water and extract with dichloromethane and washed three times with brine. The combined organic layer was then dried over sodium sulphate, and the solvent removed under reduced pressure to give a dark blue solid. The product was purified by silica gel column chromatography using hexane/chloroform as eluent to give crystal powder (480 mg, 8%).  $^1\text{H NMR}$  (600 MHz,  $\text{CDCl}_3$ )  $\delta$  8.18 (d, 2H), 8.04 (d, 2H), 7.80 (d, 2H), 7.73 (m, 2H), 7.60 (d, 1H), 7.53 (m, 3H), 7.42 (m, 3H), 7.36 (m, 1H), 7.20 (t, 1H), 7.15 (t, 1H), 7.07 (s, 1H).

**Synthesis of DTDPAB.** (See Scheme 2) To a solution of **M3** (200 mg, 0.433 mmol, 1 eq.) in dry dichloroethane is added *N,N*-diisopropylethylamine (DIPEA, 280 mg, 2.16 mmol, 5 eq.) and the mixture is left under stirring for 1 h. Then boron trifluoride diethyl etherate ( $\text{BF}_3 \cdot \text{OEt}_2$ ), is added and the mixture heated to reflux. After 2 h the mixture is cooled to room temperature and the crude diluted with dichloromethane and washed with water and brine. The organic layer was dried over magnesium sulphate and the solvent removed under reduced pressure. The product was purified by silica gel chromatography using hexane/ethyl acetate as eluent to give a coppery shining powder (180 mg, 81% yield).  $^1\text{H NMR}$  (600 MHz,  $\text{CDCl}_3$ )  $\delta$  8.41 (d, 2H), 8.08 (d, 2H), 7.66 (d, 2H), 7.47 (m, 6H), 7.30 (t, 2H), 7.21 (s, 2H).  $^{13}\text{C-NMR}$  (400 MHz,  $\text{CDCl}_3$ )  $\delta$  151.81, 147.64, 144.86, 136.13,

135.19, 135.11, 135.03, 134.15, 133.73, 131.86, 131.39, 131.27, 130.57, 120.65; mp > 297 °C with decomposition. NMR spectra of DTDPAB are presented in Fig. S1 and S2 (ESI $^\dagger$ ).

**Synthesis of F8BT-TTBT.** Synthesis route of the polymer is presented in Scheme S1 (ESI $^\dagger$ ). A mixture of 1,4,7-dibromo-2,1,3-benzothiadiazole (292 mg, 0.99 mmol, 1 eq.), 9,9-dioctyl-9H-fluorene-2,7-diboronic acid bis(pinacol) ester (500 mg, 0.89 mmol, 0.9 eq.), 2,2'-bithiophene-5,5'-diboronic acid pinacol ester (42 mg, 0.01 mmol, 0.1 eq.), tetrakis(triphenylphosphine)palladium (22 mg, 2% mol) and catalytic amount of TEBA (Benzyltriethylammonium chloride) was added in a pre-degassed Schlenk flask, followed by three vacuum/nitrogen cycles. Then degassed toluene (18 ml) and potassium carbonate 2 M water solution (4.5 ml) were added. The mixture was heated under stirring at 100 °C for 12 h then was end-capped with bromobenzene and phenyl boronic acid. The polymer was purified by precipitation in methanol and washed using a Soxhlet apparatus with methanol, hexane and chloroform. The chloroform fraction was concentrated under reduced pressure, precipitated in methanol, filtered and dried in vacuum to give a red-orange powder (102 mg, 49% yield).  $^1\text{H NMR}$  (600 MHz,  $\text{CDCl}_3$ )  $\delta$  8.1–7.3 (ArH), 2.15(s, 4H), 1.2–1.1 (m, 20H), 0.96(m, 4H), 0.81(m, 6H).  $^{13}\text{C NMR}$  (400 MHz,  $\text{CDCl}_3$ )  $\delta$  156.40, 156.28, 156.17, 156.00, 155.36, 154.79, 153.87, 153.80, 152.54, 145.66, 143.30, 143.19, 142.92, 142.69, 139.57, 138.67, 138.50, 138.19, 137.46, 136.50, 135.88, 135.64, 135.55, 135.15, 134.32, 131.28, 130.97, 130.81, 130.55, 130.35, 130.22, 130.00, 126.05, 122.14, 122.08, 114.80, 85.76, 57.47, 57.32, 42.48, 42.24, 33.68, 32.14, 32.09, 31.27, 26.97, 26.08, 25.86, 24.63, 16.09.  $^1\text{H-NMR}$  and  $^{13}\text{C-NMR}$  spectra of F8BT-TTBT are presented in Fig. S3 and S4 (ESI $^\dagger$ ).

## Devices assembly and characterization

**Devices fabrication.** Glass substrates (2.5 cm  $\times$  2.5 cm) patterned with 1 cm wide indium tin oxide (ITO) stripe were cleaned ultrasonically in distilled water, acetone and two times in isopropyl alcohol. In a case of direct architecture devices, the substrates were treated with oxygen plasma for 10 minutes and then poly(3,4-ethylene-dioxythiophene)/poly(styrenesulfonate) (PEDOT:PSS, Heraeus Clevis AI 4083) was spincoated on them through nylon filter (0.45  $\mu\text{m}$ ) at rotation 2000 rpm. Subsequently, the substrates were annealed at 100 °C for 10 minutes. Afterwards, poly(9-vinylcarbazole) (PVK,  $10^6 \text{ g mol}^{-1}$ , Sigma-Aldrich) was spincoated from chlorobenzene (10 mg  $\text{ml}^{-1}$ ) inside nitrogen filled glovebox and the substrates were annealed at 100 °C for 30 minutes.

In the case of inverted structure devices, zinc oxide (ZnO) nanocrystals (Avantama, N-10) were diluted in isopropanol solution (from 2.5% to 1.6% wt) and put in ultrasonic bath for 30 minutes. Such prepared solution was spined at 1000 rpm on the cleaned ITO substrates which were treated before deposition with UV-ozone for 1 minute. Afterwards, the substrates were annealed at 120 °C for 20 minutes in air. Next, polyethylenimine, 80% ethoxylated (PEIE, 35–40% wt in water, average  $M_w \sim 70\,000$ , Aldrich) solution in 2-methoxyethanol (3.9 mg  $\text{ml}^{-1}$ ) was spincoated on the ZnO covered substrates at



5000 rpm rotation. Substrates preparation was concluded with 10 minutes annealing at 100 °C.

Two types of emitting layers were employed in direct-driven devices on the PVK covered substrates: (i) 95% **F8BT**: 5% **DTDPAB** and (ii) 40% **F8BT**: 10% **F8BT-TTBT**: 50% **DTDPAB**, where **F8BT** stands for commercially available poly[(9,9-dioctylfluorenyl-2,7-diyl)-*alt*-co-(1,4-benzo-{2,1',3'}-thiadiazole)] (American Dye Source, ADS133YE), while **F8BT-TTBT** denotes poly(9,9-dioctylfluorene-*alt*-benzothiadiazole)(dithienyl-benzothiadiazole) and **DTDPAB** – dithienyl diphenyl AZABODIPY, both synthesized in our laboratory. The ratio in the recipes is based on weights and the final concentration of the emitting layers' solutions was 15 mg ml<sup>-1</sup>. The compounds were dissolved in extra dry toluene and left overnight at 50 °C with stirring. The emitting layers were spined inside nitrogen filled glovebox at 2000 rpm rotation in a case of the first type device and at 800 rpm in the case of the second one. In the case of the second diode, on the emitting layer 35 nm of 1,3,5-tris(1-phenyl-1*H*-benzimidazol-2-yl)benzene (TPBi, Ontario Chemicals, Inc.) was evaporated with rate 0.2 Å s<sup>-1</sup> at 3 × 10<sup>-7</sup> mbar pressure. Finally, cathodes consisting of 7 nm of barium and 100 nm of aluminium were evaporated at 1 × 10<sup>-6</sup> mbar.

In the case of inverted structure diodes, the emitting layers were prepared the same way as in the case of the second direct architecture device. Subsequently, 4,4'-bis(*N*-carbazolyl)-1,1'-biphenyl (CBP, Sigma-Aldrich) was evaporated with rate 0.2 Å s<sup>-1</sup> at 3 × 10<sup>-7</sup> mbar pressure, creating the 35 nm thick hole transporting layers. As anodes either 10 nm thick MoO<sub>3</sub> layer covered with 100 nm of aluminium or 50 nm of gold were used. The active area of a single pixel was 6.1 mm<sup>2</sup>.

In case of hole-only and electron-only devices used for mobility determination, they had structures ITO/PEDOT:PSS/40% **F8BT**: 10% **F8BT-TTBT**: 50% **DTDPAB**/MoO<sub>3</sub>/Al and ITO/ZnO/PEIE/40% **F8BT**: 10% **F8BT-TTBT**: 50% **DTDPAB**/Ba/Al, respectively. Devices constructed for the charge balance verification had on the top of the emitting layer evaporated CBP layer and the same electrodes and charge injecting layers as for the hole-only and electron-only devices.

**Characterization setups.** Electroluminescence spectra were recorded with a liquid-nitrogen-cooled CCD combined with a monochromator (Spex 270M), while the spectrum of the final device (with gold electrode) was collected with Ocean Optics Maya 2000 Pro spectrometer. Electrical characterization was performed with Keithley 2602 source meter in conjunction with a calibrated photodiode. External quantum efficiency (EQE) was calculated by measuring the light emitted in the forward direction with Lambertian source assumption. Measurements of all devices were done by applying constant biases to the diodes in nitrogen atmosphere at room temperature.

Electrochemistry was performed at room temperature in acetonitrile under nitrogen in three electrode cells. The counter electrode was platinum; reference electrode was Ag/Ag<sup>+</sup> (0.1 M AgNO<sub>3</sub> in acetonitrile, 0.34 V vs. SCE, -4.73 V vs. vacuum), supporting electrolyte was 0.1 M tetrabutylammonium perchlorate (TBAP). Cyclic Voltammetry was performed at a scan rate of 0.1 V s<sup>-1</sup>. Working electrode was glassy carbon (GC, 0.2 cm<sup>2</sup>).

**F8BT**, **F8BT-TTBT**, **DTDPAB** films were casted onto electrodes at 80–90 °C from 1 mg mL<sup>-1</sup> solutions in chloroform (2 mL). The voltammetric apparatus was Metrohm Autolab 128N potentiostat/galvanostat.

Photoluminescence (PL) spectra were obtained with a Nano-Log composed by the iH320 spectrograph equipped with the Synapse QExtra charge-coupled device by exciting with a monochromated 450 W Xe lamp. The spectra are corrected for the instrument response. Time-resolved TCSPC measurements were obtained with PPD-850 single photon detector module and DD-405L DeltaDiode Laser and analysed with the instrument Software DAS6.

## Results and discussion

### Synthesis

The thienyl substituted AZABODIPY (**DTDPAB**) is synthesized according to the literature<sup>36,37</sup> and described in detail in the experimental section and in Scheme 2. The first step is the synthesis of the chalcone **M1** with the condensation of 2-acetylthiophene and benzaldehyde. The intermediate phenyl 4-nitro-3-thienylbutan-1-one **M2** is obtained in the second step by reacting the obtained **M1** with nitromethane and potassium carbonate. Subsequently **M2** is used in the next step without further purification reacting with ammonium acetate to obtain the azadipyrromethene derivative **M3**. In the last step *N,N*-diisopropylethylamine with boron trifluoride diethyl etherate react with **M3** to give the final product dithieno-diphenyl-azabodipy.

The polymeric host **F8BT-TTBT** (see Scheme 1) is a random tercopolymer synthesized *via* standard Suzuki polymerization conditions by using toluene as a solvent and Pd(0) as a catalyst. The bithiophene-based monomer responsible for the red shift of the emission has been added in a percentage of 10%. Our previous studies have shown that with these percentages a complete energy transfer in the emission is obtained and the energy levels are comparable with the parent **F8BT**.<sup>9</sup>

### Optoelectronic and electrochemical properties

In Fig. 1(a) the absorption, PL excitation and PL spectra of **DTDPAB** in solution are presented. The absorption spectrum displays three main bands peaked at 345 nm, 475 nm and 720 nm. The PL spectrum has a sharp peak at 733 nm with a band, very probably a vibronic replica, at about 800 nm, with excitation spectra closely corresponding to the absorption. The emission properties do not display significant variations with the solvent (see Table S1 and Fig. S5 and S6, ESI<sup>†</sup>) with PL Quantum Yield of 0.43 and lifetime of 3.3 ns in chloroform. These findings correspond well with the results presented by Zhang *et al.* in ref. 36. The PL emission is the mirror image of the absorption peaks at the longest wavelengths. The small Stokes shift (30 meV) suggests that the molecule possesses high rigidity and consequently should not dissipate much energy, an important property for a NIR emitter influenced by the energy gap law.



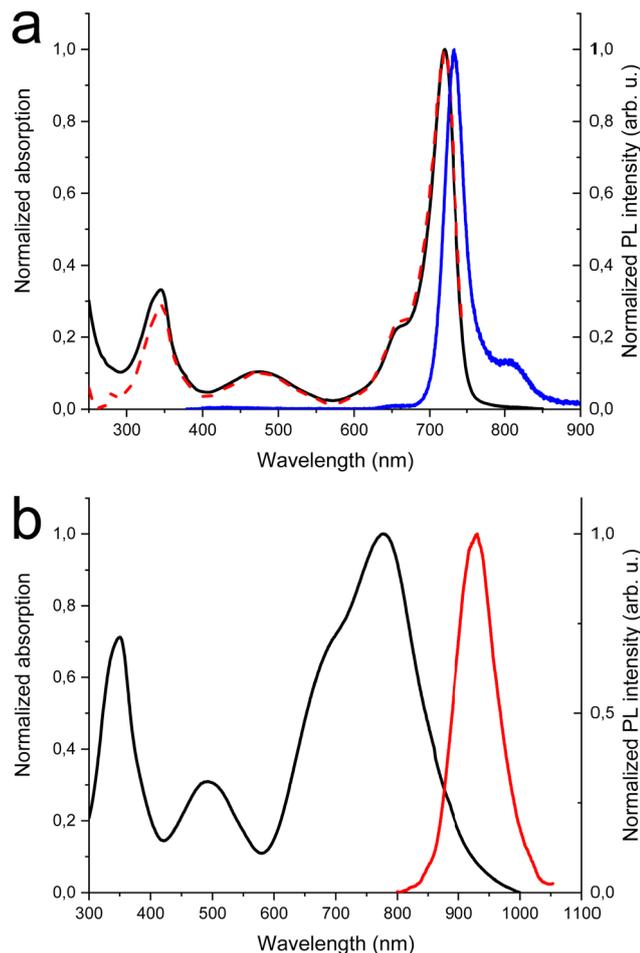


Fig. 1 (a) Absorption (black solid), excitation (red dash) and PL (blue solid) spectra of **DTDPAB** in chloroform ( $c = 10^{-5}$  M), (b) absorption (black solid) and PL (red solid) spectra of **DTDPAB** cast film.

Fig. 1(b) shows the absorption and PL spectra of **DTDPAB** in the solid state. With respect to the absorption spectra in solutions, the longest wavelength absorption band of the film displays a large broadening and red-shifts to 777 nm. Accordingly, the PL spectrum is red-shifted to 930 nm. Moreover, the PL intensity is drastically reduced, with a PLQY below the sensitivity of our instrument (0.1%). The PL decay profile (Fig. S7, ESI<sup>†</sup>) is much faster than in solution, displaying a lifetime of about 300 ps. The PL properties of **DTDPAB** cast films indicate the presence of efficient emission quenching processes in the solid state, as often observed for organic moieties displaying strong intermolecular interactions upon aggregation in thin films, powders and crystals.<sup>41,42</sup>

The CVs analyses show that **F8BT** film presents one irreversible oxidation process at 1.08 V (Fig. S8, Table S2, ESI<sup>†</sup> and Table 1) which may interest the fluorene moiety. In **F8BT-TTBT** film the oxidation process splits into two peaks at 1.06 V and 1.13 V (Fig. S9, Table S2, ESI<sup>†</sup> and Table 1), where the second peak may be ascribed to the bithiophene moiety. Both polymers present one reversible reduction process at comparable potentials which may be due the fluorene moiety. The CV response of

Table 1 Film oxidation and reduction potentials measured with cyclic voltammetry, calculated from them HOMO and LUMO levels and the energy band gaps of the materials used in this study

	$E_{\text{ox}}$	$E_{\text{red}}$	HOMO	LUMO	$E_{\text{gcv}}$
<b>DTDPAB</b>	0.57	-0.65	-5.30	-4.08	1.22
<b>F8BT-TTBT</b>	0.97	-1.8	-5.70	-2.93	2.77
<b>F8BT</b>	0.99	-1.84	-5.72	-2.89	2.83

**DTDPAB** in solid-state films results to be more complex than in solution: the oxidation response splits into three peaks at 0.7 V, 0.82 V, and 1.39 V while the two reduction ones become irreversible (Fig. 2, Fig. S10, Table S2, ESI<sup>†</sup> and Table 1).<sup>36</sup> A possible explanation is that the CV response may be severely affected by the solid-state conditions such as different aggregation or amorphous phases.<sup>43</sup>

The nitrogen atom replacing the carbon atom in the *meso* position of **DTDPAB** induces the desired bathochromic shift without increasing molecular size and weight and maintaining good solubility. Compared to the parent BODIPY, the electro-negativity of nitrogen induces a preferable stabilization of the LUMO state, reducing the energy gap (see Table S2, ESI<sup>†</sup>). Contemporarily the electro-donating thiophene substituents increase the HOMO level, while the LUMO level remains nearly constant, resulting in a further reduced energy gap with a bathochromic shift. Furthermore, less steric hindrance of thienyl five-member ring with respect to the six-member phenyl ring allows for greater coplanarity enhancing the electron delocalization.

As regards the polymeric hosts, the main optoelectronic characteristics are shown in Table 1 and Fig. S11 (ESI<sup>†</sup>). As anticipated, the two polymers have comparable energy levels as expected from the low percentage of the thiophene monomer with respect to the **F8BT** one. The optical properties of the two polymers differ in an evident way as concerns the emission, in fact **F8BT** and **F8BT-TTBT** have the PL at 555 nm and 660 nm,

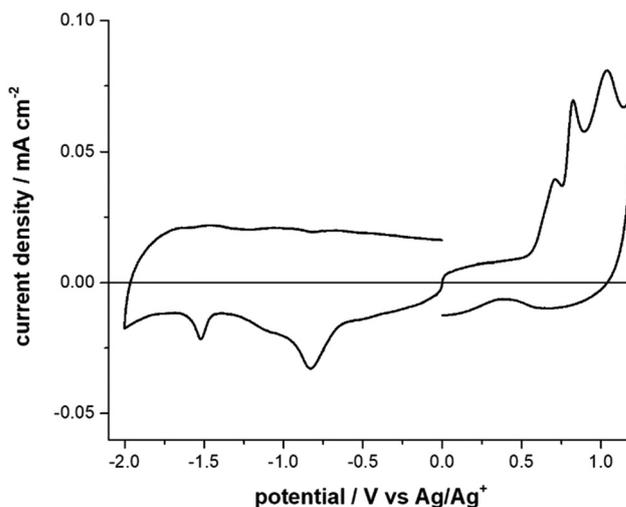


Fig. 2 Cyclic Voltammograms of **DTDPAB** molecule, in acetonitrile + 0.1 M  $\text{Bu}_4\text{NClO}_4$ . Scan rate:  $0.1 \text{ V s}^{-1}$ .



respectively, while in the absorption their spectra are similar with addition of a small band at 550 nm in the case of the polymer with thiophenes.

### Electroluminescence performance

The first device to test **DTDPAB** abilities as an emitter had simple yet multilayer direct architecture ITO/PEDOT:PSS/PVK/95% **F8BT**: 5% **DTDPAB**/Ba/Al. All organic films were deposited by spincoating technique which is cheaper and faster than thermal evaporation processing. High molecular weight PVK deposited on PEDOT:PSS plays a role of hole transporting layer and allows deposition of the emitting layer from solution. Simultaneously, PVK prevents radiative excitons from quenching caused by the acidic nature of PEDOT:PSS.<sup>9</sup> Additionally, the shallower LUMO level of PVK (−2.3 eV) with respect to the deeper LUMO of **F8BT** (−2.89 eV) blocks electrons traveling towards the anode and prevents in this way the leakage current.

Fig. 3 presents the EL spectrum of the device. Contributions from **F8BT** (500–650 nm) and **DTDPAB** (700–900 nm) to the spectrum are clearly distinguishable and correspond to their PL spectra, while PVK emission is not present in the EL. The **F8BT** band has a typical form for this polymer, while **DTDPAB** EL spectrum displays a 30 nm red-shift (the peak at 760 nm and the shoulder at 835 nm) with respect to the PL in solution, revealing intermediate characteristics between the solution and solid state as expected in a blend. Moreover, the long wavelength shoulder in the EL spectrum is more pronounced than in chloroform, probably due to the **DTDPAB** aggregate emission.

The presence of **F8BT** emission in the EL spectrum is the evidence that energy transfer from the host to **DTDPAB** is not particularly efficient. The cause of this is the poor overlap of the **F8BT** emission and the guest absorption, as envisaged in Fig. S11 (ESI†).

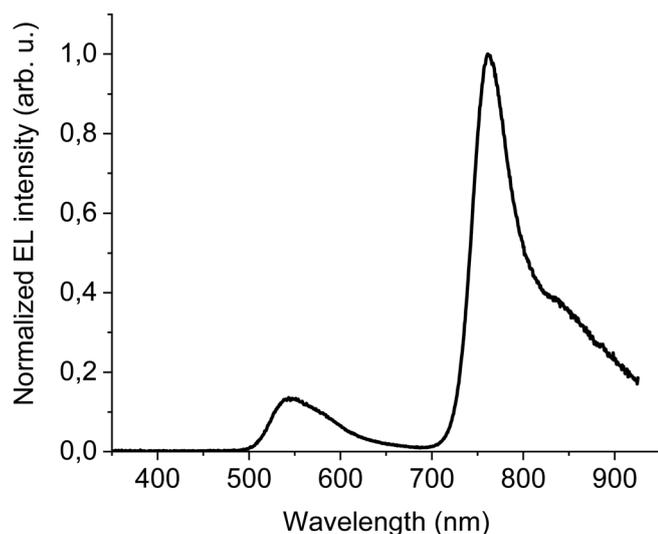


Fig. 3 EL at 100 mA cm<sup>−2</sup> of ITO/PEDOT:PSS/PVK/95% **F8BT**: 5% **DTDPAB**/Ba/Al direct architecture device.

The results of electrical characterization of the device are shown in Fig. S12 (ESI†) and in Table 2. The turn-on voltage is equal to 8 V and corresponds to the quite high current density of  $1.2 \times 10^{-4}$  A cm<sup>−2</sup>. The maximal recorded radiance is equal to moderate 0.58 W sr<sup>−1</sup> m<sup>−2</sup> which in combination with high current densities gives as a result modest maximal EQE of 0.04%.

Intrigued by the **DTDPAB** spectrum, we built a device with highly concentrated guest molecule to determine if the emission can be further shifted towards NIR spectral region. In Fig. S13 (ESI†), the EL spectrum of the diode with emitting layer (EML) consisting of 80% **DTDPAB** in **F8BT** matrix is presented. The spectrum is dominated by a broad band centred at 950 nm with a peak at 760 nm originating from single **DTDPAB** molecules, however, the **F8BT** band is still visible. The EQE of the device decreased one order of magnitude in comparison to the diode with low guest concentration due to the concentration quenching<sup>44</sup> (Fig. S14, ESI†).

In order to improve the efficiency, we decided to add **F8BT-TTBT** polymer to the emissive layer's components and at the same time to decrease concentration of **DTDPAB** to 50%. The task of the new polymer is to improve energy transfer from the matrix to the guest molecules thanks to the better overlap of their spectra (Fig. S11, ESI†). The decreased emitter concentration should diminish concentration quenching. Finally, we introduced thermally evaporated TPBi as an electron transporting layer (ETL) to separate recombination zone from the cathode and to avoid in this way plasmon creation in the electrode. TPBi should also block a leakage current of holes thanks to the deep HOMO level<sup>45</sup> (see Fig. 4(a)). EL spectrum of this new diode is shown in Fig. 5.

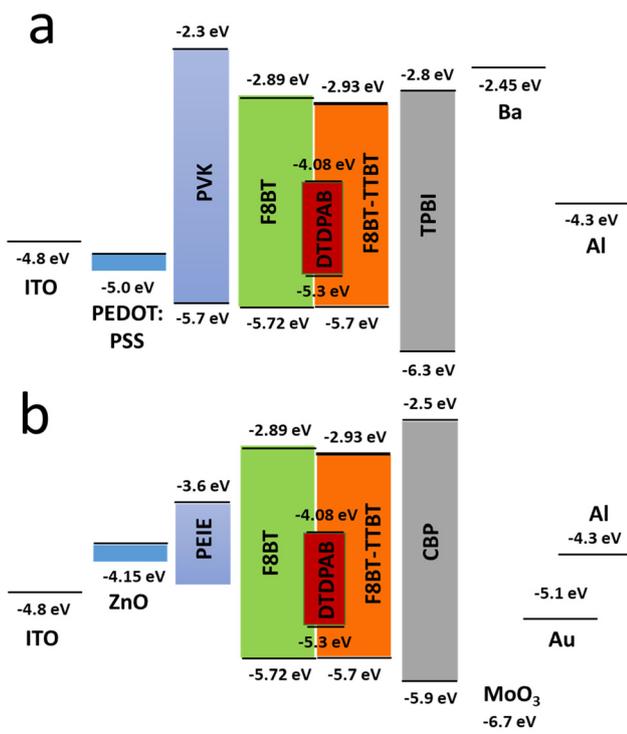
The emission of the **DTDPAB** molecule is better resolved than in the previous cases but resembles earlier registered EL spectra, the **F8BT** band is also visible. On the other hand, the EL from **F8BT-TTBT** is not present which suggests successful energy transfer from the polymer to the dopant. The confirmation of this process is presented in Fig. S15 (ESI†), where a device with the emitting layer composed of 80% **F8BT**: 20% **F8BT-TTBT** (the same hosts ratio as in the device in Fig. 5 but without **DTDPAB**) shows electroluminescence solely from **F8BT-TTBT**. Therefore, energy transfer together with the dopant concentration adjustment creates the possibility of spectrum control depending on the particular application needs: when simultaneous emission in visible and NIR is required, a non-transferring matrix can be used while for pure NIR emission polymer with good overlap with the acceptor should be applied.

The new band in the EL spectrum in the UV-blue region is associated with TPBi electroluminescence.<sup>46</sup> This emission cannot originate from PVK since the LEDs with this polymer but without TPBi layer do not emit in this spectral range (see Fig. 3 and Fig. S13, ESI†) and also the PVK electroluminescence is placed at longer wavelengths (Fig. S16, ESI†). The EQE of the device is equal to 0.009% (Fig. S17, ESI†), which is higher than for the diode without **F8BT-TTBT** and TPBi (EQE = 0.003%) but lower than for the LED with low **DTDPAB** concentration. It is reasonable to assume that big contribution of TPBi and the



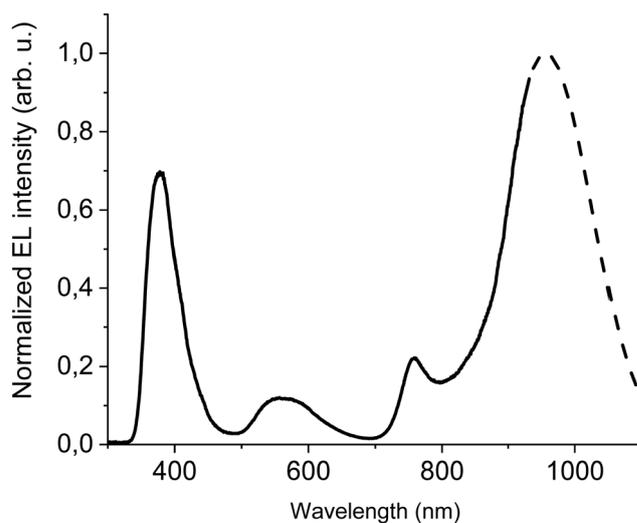
**Table 2** Structures, peak wavelengths, the maximal external quantum efficiencies and the fraction of photons emitted in NIR for the chosen devices. The EQE values precision is estimated to be  $\pm 0.0005$

Structure	Peak wavelength (nm)	EQE <sub>max</sub> (%)	EL in NIR (> 700 nm %)
ITO/PEDOT:PSS/PVK/95% <b>F8BT</b> : 5% <b>DTDPAB</b> /Ba/Al	550, 760	0.0413	89
ITO/PEDOT:PSS/PVK/40% <b>F8BT</b> : 10% <b>F8BT-TTBT</b> : 50% <b>DTDPAB</b> /TPBi/Ba/Al	378, 550, 758, >900	0.0090	75
ITO/ZnO/PEIE/40% <b>F8BT</b> : 10% <b>F8BT-TTBT</b> : 50% <b>DTDPAB</b> /CBP/MoO <sub>3</sub> /Al	>900	0.0018	100
ITO/ZnO/PEIE/40% <b>F8BT</b> : 10% <b>F8BT-TTBT</b> : 50% <b>DTDPAB</b> /CBP/Au	785, 910	0.0027	100



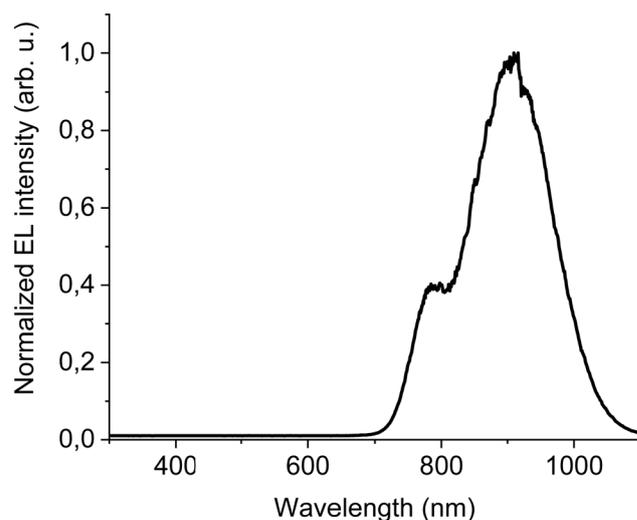
**Fig. 4** Energy levels of all materials employed in the direct (a) and inverted (b) devices. For the configuration of a specific diode see text.

polymers to the total emission had influence on the EQE of the device. Turn-on voltage increased to 10 V due to a higher thickness of the device. Since we were interested in pure NIR emission, changes in the diode design were necessary. Visible TPBi EL is clear evidence that the recombination zone is at the EML/ETL interface. In order to avoid emission from the transporting layer we decided to apply an inverted architecture in the form ITO/ZnO/PEIE/40% **F8BT**: 10% **F8BT-TTBT**: 50% **DTDPAB**/CBP/MoO<sub>3</sub>/Al. The EL spectrum of the device is shown in Fig. S18 (ESI<sup>†</sup>) and is purely in the NIR spectral region (>700 nm) which may suggest that the recombination zone was moved towards PEIE/EML interface. However, the maximal EQE of the diode decreased to 0.0018% (Fig. S19, ESI<sup>†</sup>). Suspecting that this drop in the EQE may be caused by too facile injection of holes thanks to the deep lying MoO<sub>3</sub> energy level (see Fig. 4(b)) we substituted this anode with a gold electrode. As a result, the maximal EQE increased to 0.0027% preserving at the same time purely NIR emission with the maximum at 910 nm (Fig. S20, ESI<sup>†</sup> and Fig. 6, respectively).



**Fig. 5** EL at 100 mA cm<sup>-2</sup> of ITO/PEDOT:PSS/PVK/40% **F8BT**: 10% **F8BT-TTBT**: 50% **DTDPAB**/TPBi/Ba/Al device. Dashed line shows simulated extrapolation of the spectrum.

To understand better the origin of the low EQE values, we built and characterized electron-only and hole-only devices with the EML layer. Subsequently, we extracted electron and hole mobilities in the emitting layer, applying the Mott–Gurney



**Fig. 6** EL at 100 mA cm<sup>-2</sup> of ITO/ZnO/PEIE/40% **F8BT**: 10% **F8BT-TTBT**: 50% **DTDPAB**/CBP/Au inverted architecture device.



law for the field range where the currents were limited by a space charge (SCLC),

$$J_{\text{SCLC}} = \frac{9}{8} \epsilon_0 \epsilon_r \mu \frac{F^2}{d}$$

Here,  $J$  is the current density of either holes or electrons,  $\epsilon_0$  denotes the vacuum permittivity,  $\epsilon_r$  stands for the relative permittivity,  $\mu$  is the mobility of either holes or electrons and the electric field is  $F = U/d$ , where  $d$  denotes the distance between the electrodes and  $U$  is the applied voltage. The results of those measurements are presented in Fig. S21 and S22 (ESI<sup>†</sup>) and show that the mobility of electrons in the emitting layer is one order of magnitude higher than holes ( $\mu_e = 2.5 \times 10^{-5} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$  vs.  $\mu_h = 2.2 \times 10^{-6} \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ ). However, it should be pointed out that the mobilities alone can't give information about the carriers imbalance in the device since there are other factors that influence this parameter. We therefore built and characterized electron-only and hole-only devices with structure EML/CBP to simulate better the real diode with inverted architecture. The results of those measurements are presented in Fig. S23 (ESI<sup>†</sup>) and show that the electron and hole currents are imbalanced at the most of applied voltages, the only moment when they are equal is at 9 V. Since the EQE of a device is directly proportional to the charge balance within it, we can confront the electron and hole currents in Fig. S23 (ESI<sup>†</sup>) and the EQE curves in Fig. S19 and S20 (ESI<sup>†</sup>). The both EQEs are not stable, they rise at small current densities and reach their maximal values for the current densities corresponding roughly to 9 V. This fact correlates well with the two types of currents behaviour presented in Fig. S23 (ESI<sup>†</sup>), therefore we can conclude that the charge imbalance is one of the reasons of low EQE of the devices. However, the main factors are concentration quenching which decreases PLQY in the solid state and the energy gap law. Additionally, as reported in ref. 40, the DTDPAB molecule suffers from the photoinduced absorption in the spectral range of the aggregates emission which is another efficiency loss mechanism.

## Conclusions

Organic emitters play a role of increasing interest thanks to the multiple fields of application. However, to obtain materials capable of efficient emission in the deep infrared region (over 850 nm) has proved to be an unresolved challenge for chemists.

In fact, to realize an emitter with these characteristics, the difference between the HOMO–LUMO energy levels must be lower than 1.46 eV and this often leads to a low air stability. Moreover, these materials being generally formed by planar conjugate systems, easily aggregate suffering from aggregation quenching which combined with the energy gap law are the main limitations to obtain the objective. On the other hand, the possibility of getting emissive aggregates from smaller molecules can lead to a simplification of the synthesis with respect to large conjugated structures.

In the present work we were able to obtain emissive aggregates of the AZABODIPY derivative and this allowed to red shift the maximum emission from 733 nm in solution, to 760 nm in

the blend without aggregates and up to 930 nm in the case of emissive aggregates. A further important result was the electroluminescence achieved from these clusters. Through the study of the geometry of the device, direct and inverted, the use of charge regulating layers, and the choice of suitable polymeric hosts, a pure emission in NIR with the maximum at 910 nm was obtained. Up to our knowledge, this is the first example of electrically excited single AZABODIPY emitter that emits in real NIR (>700 nm).

This result is a proof of concept that paves the way for the development and application of AZABODIPYs as electroluminescent emitters in NIR. Furthermore, the approach introduced in the present work can be a valid suggestion to deepen the study of other already known materials that could show the same type of behaviour.

## Author contributions

B. M. S. synthesized the materials, interpreted NMR spectra and with B. V. performed electrochemical characterization, C. B. measured photophysical properties, W. M. fabricated and characterized the devices, M. P. supervised the work. All authors contributed to the data analysis, discussed the results, and contributed to the writing of the manuscript.

## Conflicts of interest

There are no conflicts to declare.

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